NPN Epitaxial Silicon Transistor

KSC1845

Features

- Audio Frequency Low-Noise Amplifier
- Complement to KSA992
- This is a Pb–Free Device

MAXIMUM RATINGS (Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

| Symbol | Parameter | Value | Unit |
|------------------|---------------------------|------------|------|
| V _{CBO} | Collector-Base Voltage | 120 | V |
| V _{CEO} | Collector-Emitter Voltage | 120 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| Ι _C | Collector Current | 50 | mA |
| Ι _Β | Base Current | 10 | mA |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | –55 to 150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Values are at $T_A = 25^{\circ}C$ unless otherwise noted.) (Note 1)

| Symbol | Parameter | Value | Unit |
|---------------|--|-------|-------|
| PD | Power Dissipation | 500 | mW |
| | Derate Above 25°C | 4 | mW/°C |
| $R_{	hetaJA}$ | Thermal Resistance, Junction-to-Ambient | 250 | °C/W |

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

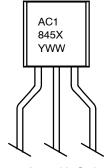


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MARKING DIAGRAM



ORDERING INFORMATION

| Device | Package | Shipping |
|------------|-----------------------|-----------------|
| KSC1845FTA | TO–92 3L (Pb–Free) | 2000 / Fan-Fold |

KSC1845

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--------------------------------------|---|------|------|------|------|
| BV_{CBO} | Collector-Base Breakdown Voltage | I _C = 100 μA, I _A = 0 | 120 | - | - | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = 1 mA, I _B = 0 | 120 | - | - | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | I _E = 100 μA, I _C = 0 | 5 | - | - | V |
| I _{CBO} | Collector Cut-Off Current | V _{CB} = 120 V, I _E = 0 | - | - | 50 | nA |
| I _{EBO} | Emitter Cut-Off Current | $V_{EB} = 5 V, I_{C} = 0$ | - | - | 50 | nA |
| h _{FE1} | DC Current Gain | $V_{CE} = 6 \text{ V}, \text{ I}_{C} = 0.1 \text{ mA}$ | 150 | 580 | - | |
| h _{FE2} | | $V_{CE} = 6 V, I_{C} = 1 mA$ | 200 | 600 | 1200 | |
| V _{BE} (on) | Base-Emitter On Voltage | V_{CE} = 6 V, I_C = 1 mA | 0.55 | 0.59 | 0.65 | V |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = 10 mA, I _B = 1 mA | - | 0.07 | 0.30 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} = 6 V, I _C = 1 mA | 50 | 100 | - | MHz |
| C _{ob} | Output Capacitance | V _{CB} = 30 V, I _E = 0, f = 1 MHz | - | 1.6 | 2.5 | pF |
| NF | Noise Figure | $\label{eq:Vce} \begin{array}{l} V_{CE} = -5 \ \text{V}, \ \text{I}_{C} = -1.0 \ \text{mA}, \\ R_{S} = 100 \ \text{k}\Omega, \ \text{f} = 1 \ \text{kHz} \end{array}$ | - | 7 | _ | dB |

ELECTRICAL CHARACTERISTICS (Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

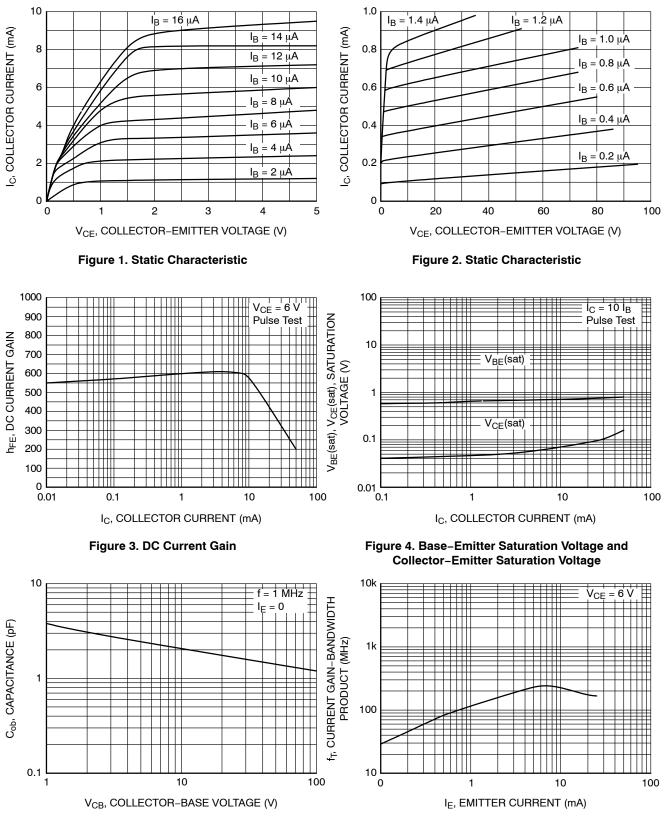
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

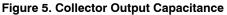
h_{FE} CLASSIFICATION

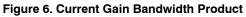
| Classification | Р | F | E | U |
|------------------|---------|---------|---------|----------|
| h _{FE2} | 200~400 | 300~600 | 400~800 | 600~1200 |

KSC1845

TYPICAL PERFORMANCE CHARACTERISTICS







KSC1845

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

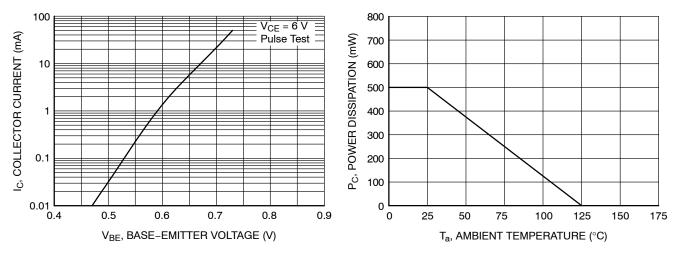
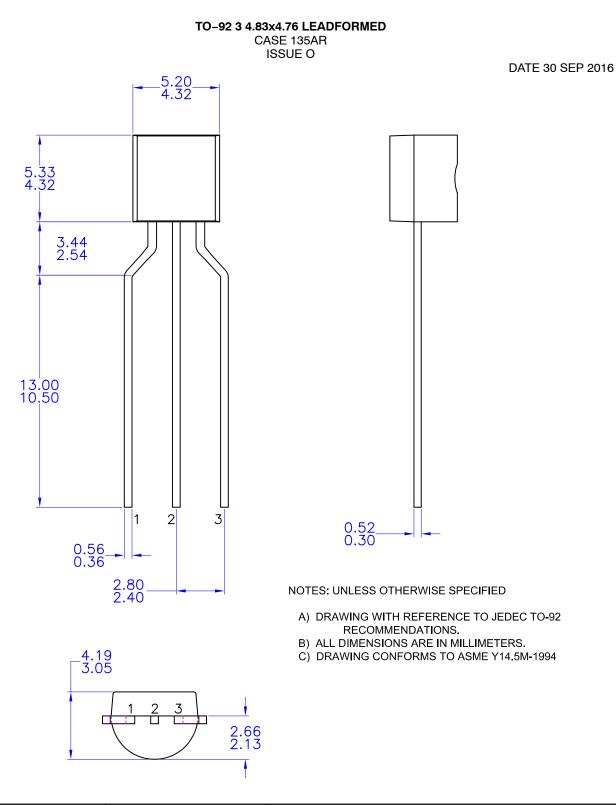


Figure 7. Collector Current vs. Base-Emitter Voltage







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